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Kind regards,

Team Nexperia



# **PMBD7000**

# Double high-speed switching diode Rev. 4 — 16 September 2010

**Product data sheet** 

## **Product profile**

## 1.1 General description

The PMBD7000 consists of two high-speed switching diodes connected in series, fabricated in planar technology, and encapsulated in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- High switching speed:  $t_{rr} \le 4$  ns
- Repetitive peak forward current:  $I_{FRM} \le 450 \text{ mA}$
- Small SMD plastic package
- Reverse voltage: V<sub>R</sub> ≤ 100 V
- Repetitive peak reverse voltage:  $V_{RRM} \le 100 \text{ V}$
- AEC-Q101 qualified

#### 1.3 Applications

- High-speed switching
- General-purpose switching

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>R</sub>	reverse current	$V_{R} = 100 \ V$	-	-	0.5	μΑ
$V_R$	reverse voltage		-	-	100	V
t <sub>rr</sub>	reverse recovery time		[1] -	-	4	ns

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.



#### Double high-speed switching diode

# 2. Pinning information

Table 2. Pinning

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2	1 2 006aaa763
			UU6aaa763

# 3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
PMBD7000	-	plastic surface-mounted package; 3 leads	SOT23	

## 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PMBD7000	*5C

<sup>[1] \* = -:</sup> made in Hong Kong

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

#### Double high-speed switching diode

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
$V_{RRM}$	repetitive peak reverse voltage		-	100	V
$V_R$	reverse voltage		-	100	V
I <sub>F</sub>	forward current		[1] -	215	mA
			[2] _	125	mA
I <sub>FRM</sub>	repetitive peak forward current		-	450	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave	<u>[3]</u>		
		t <sub>p</sub> = 1 μs	-	4	Α
		t <sub>p</sub> = 1 ms	-	1	Α
		t <sub>p</sub> = 1 s	-	0.5	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$	<u>[1][4]</u> _	250	mW
Per device					
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–55</b>	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Single diode loaded.

### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Mir	1 Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	500	K/W
$R_{th(j-t)}$	thermal resistance from junction to tie-point		-	-	360	K/W

<sup>[1]</sup> Single diode loaded.

<sup>[2]</sup> Double diode loaded.

<sup>[3]</sup>  $T_j = 25$  °C prior to surge.

<sup>[4]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

#### Double high-speed switching diode

### 7. Characteristics

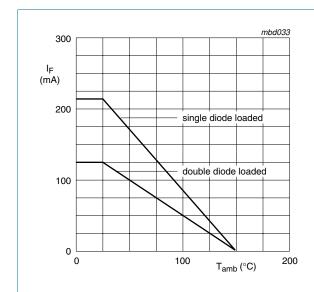
Table 7. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 1 mA	-	550	700	mV
		$I_F = 10 \text{ mA}$	-	670	820	mV
		$I_F = 50 \text{ mA}$	-	-	1	V
		I <sub>F</sub> = 100 mA	-	0.75	1.1	V
		I <sub>F</sub> = 150 mA	-	-	1.25	V
I <sub>R</sub> reverse current	reverse current	V <sub>R</sub> = 50 V	-	-	300	nA
		V <sub>R</sub> = 100 V	-	-	500	nA
		V <sub>R</sub> = 50 V; T <sub>j</sub> = 150 °C	-	-	100	μА
$C_{d}$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> -	-	4	ns
$V_{FR}$	forward recovery voltage		[2] _	-	1.75	V

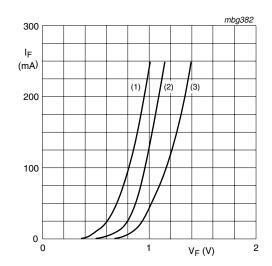
<sup>[1]</sup> When switched from  $I_F = 10$  mA to  $I_R = 10$  mA;  $R_L = 100$   $\Omega$ ; measured at  $I_R = 1$  mA.

<sup>[2]</sup> When switched from  $I_F = 10$  mA;  $t_r = 20$  ns.



FR4 PCB, standard footprint

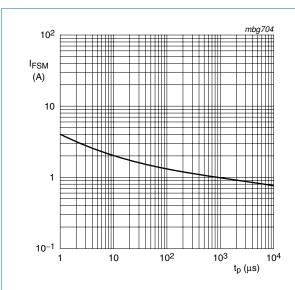
Fig 1. Forward current as a function of ambient temperature; derating curve



- (1)  $T_j = 150 \,^{\circ}C$ ; typical values
- (2)  $T_i = 25 \,^{\circ}C$ ; typical values
- (3)  $T_j = 25 \,^{\circ}C$ ; maximum values

Fig 2. Forward current as a function of forward voltage

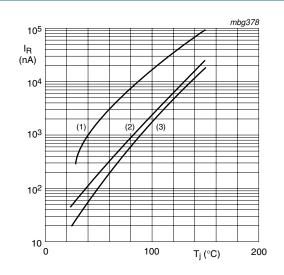
#### Double high-speed switching diode



Based on square wave currents.

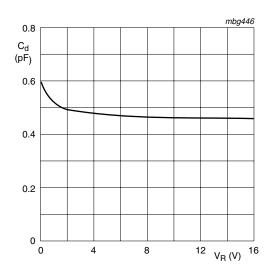
 $T_j = 25$  °C; prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1)  $V_R = 50 \text{ V}$ ; maximum values
- (2) V<sub>R</sub> = 30 V; typical values
- (3)  $V_R = 50 \text{ V}$ ; typical values

Fig 4. Reverse current as a function of junction temperature

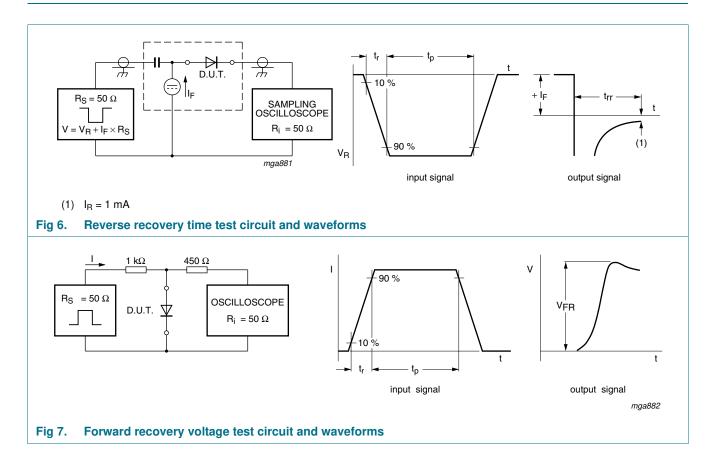


 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ 

Fig 5. Diode capacitance as a function of reverse voltage; typical values

#### Double high-speed switching diode

## 8. Test information

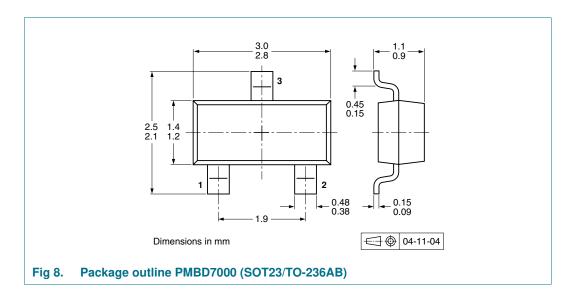


### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### Double high-speed switching diode

# 9. Package outline



# 10. Packing information

Table 8. Packing methods

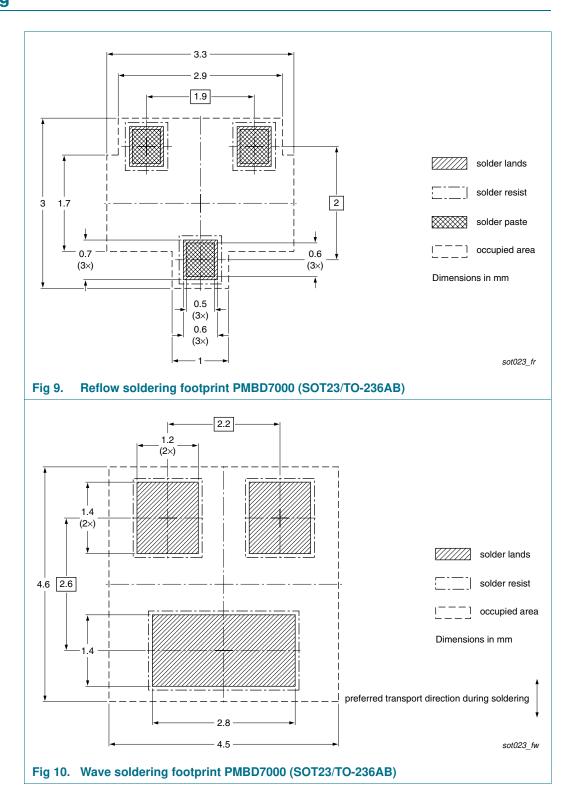
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMBD7000	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

#### Double high-speed switching diode

# 11. Soldering



## Double high-speed switching diode

# 12. Revision history

#### Table 9. Revision history

Release date	Data sheet status	Change notice	Supersedes
20100916	Product data sheet	-	PMBD7000_3
		redesigned to comply w	vith the new identity
<ul> <li>Legal texts h</li> </ul>	nave been adapted to the ne	ew company name whe	ere appropriate.
• Table 4 "Mar	king codes": updated		
• Table 7 "Cha	aracteristics": corrected V <sub>F</sub> u	unit for condition $I_F = 15$	50 mA
• Figure 2: upo	dated		
Section 8 "Te	est information": figure title	of Figure 6 amended	
<ul> <li>Section 8.1 "</li> </ul>	'Quality information": added	l	
Section 13 "I	Legal information": updated		
19990511	Product specification	-	PMBD7000_2
19960918	Product specification	-	PMBD7000 1
13300310	i roddot opcomodtion		
	20100916  The format of guidelines of Legal texts homeometric Table 4 "Mar Table 7 "Char" Figure 2: upo Section 8 "To Section 8.1" Section 13 "In 19990511	<ul> <li>20100916 Product data sheet</li> <li>The format of this data sheet has been a guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new temporaries.</li> <li>Table 4 "Marking codes": updated</li> <li>Table 7 "Characteristics": corrected V<sub>F</sub> to Figure 2: updated</li> <li>Section 8 "Test information": figure title of Section 8.1 "Quality information": added</li> <li>Section 13 "Legal information": updated</li> <li>19990511 Product specification</li> </ul>	<ul> <li>The format of this data sheet has been redesigned to comply we guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name when the temperature and the temperat</li></ul>

#### Double high-speed switching diode

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PMBD7000

#### Double high-speed switching diode

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**PMBD7000 NXP Semiconductors** 

## Double high-speed switching diode

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